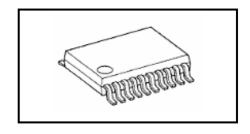
Toshiba Bi-CD Integrated Circuit Silicon Monolithic

TB6593FNG

Driver IC for DC motor

TB6593FNG is a driver IC for DC motor with output transistor in LD MOS structure with low ON-resistor. Two input signals, IN1 and IN2, can choose one of four modes such as CW, CCW, short brake, and stop mode.



Weight SSOP20-P-225-0.65: 0.09g (Typ.)

Features

Power supply voltage : VM=15V (Max.)

Output current : Iout=1.2A(ave) / 3.2A (peak) Output low ON resistor : 0.35 ((typ. @VM 5V)

• Standby (Power save)system

• CW/CCW/short brake/stop function modes

• Built-in thermal shutdown circuit and low voltage detecting circuit

Small faced package (SSOP20:0.65mm pitch)

• Response to Pb free packaging

The TB6593FNG is a Pb-free product.

The following conditions apply to solderability:

*Solderability

1. Use of Sn-63Pb solder bath

*solder bath temperature = 230°C

*dipping time = 5 seconds

*number of times = once

*use of R-type flux

2. Use of Sn-3.0Ag-0.5Cu solder bath

*solder bath temperature = 245°C

*dipping time = 5 seconds

*the number of times = once

*use of R-type flux

* This product has a MOS structure and is sensitive to electrostatic discharge. When handling this product, ensure that the environment is protected against electrostatic discharge by using an earth strap, a conductive mat and an ionizer. Ensure also that the ambient temperature and relative humidity are maintained at reasonable levels.

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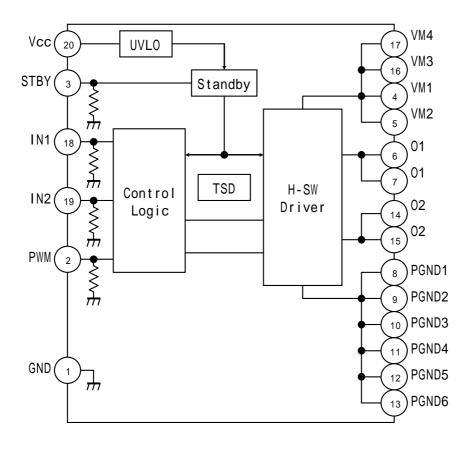


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Block Diagram



Pin Functions

Pin NO.	Symbol	Characteristics	Remarks				
1	GND	Small signal GND					
2	PWM	PWM signal input	"H"=Active / 200k pull-down at internal				
3	STBY	Standby signal input	"L"=standby / 200k pull-down at internal				
4	VM1	VM amply	VM=2.5V~13.5V				
5	VM2	VM supply					
6	01	Output1					
7	01	Output1					
8	PGND1						
9	PGND2						
10	PGND3	Power GND					
11	PGND4	rower GND					
12	PGND5						
13	PGND6						
14	O2	Outnut					
15	O2	Output2					
16	VM3	VM aumply	VM=2.5V~13.5V				
17	VM4	VM supply					
18	IN1	Control signal nput1	200k pull-down at internal				
19	IN2	Control signal input2	200k pull-down at internal				
20	Vcc	Small signal supply	Vcc=2.7V ~ 5.5V				



Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	Remarks	
Supply voltage	VM	15	V		
	Vcc	6	v		
Input voltage VIN		-0.2 ~ 6	V	IN1,IN2,STBY,PWM pins	
Output voltage Vout		15	V	O1,O2 pins	
Output current	Iout	1.2	A		
	Iout (peak)	3.2	A	tw=10ms, Superimposed pulse, Duty is 30% or less.	
Power dissipation	PD	0.96	W	50×50×1.6mm When it is packaged to the board made of glass-epoxy (Cu40%).	
		0.71		IC only	
Operating temperature	Topr	-20 ~ 85			
Storage temperature	Tstg	-55 ~ 150			

Operating Range ($Ta = -20 \text{ to } 85^{\circ}\text{C}$)

Characteristics	Symbol	Min	Тур.	Max	Unit
~ , ,	Vcc	2.7	3	5.5	V
Supply voltage	VM	2.5	5	13.5	V
Output current (H-SW)	Iout			1.0	A
Switching frequency	fPWM			100	kHz

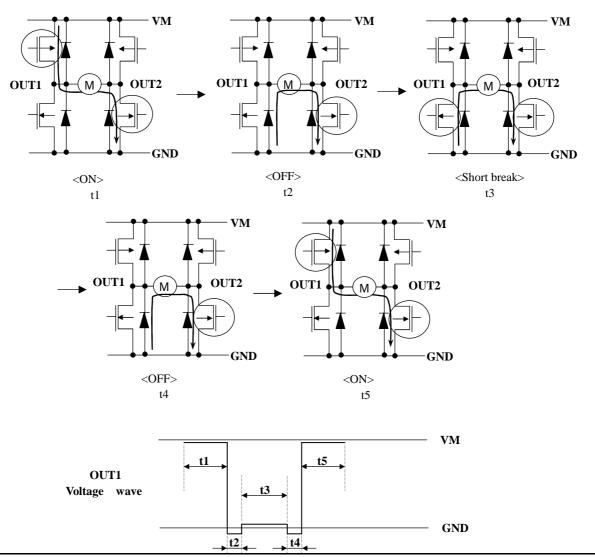
TB6593FNG

H-SW Control Function

Input				Output			
IN1	IN2	PWM	STBY	OUT1	OUT2	Mode	
Н	Н	Н	Н	L	L	Short brake	
L H	ш	н		L	Н	CCW	
	п	L	Н	L	L	Short brake	
H L	т	н	Н	Н	L	CW	
	ь	L	Н	L	L	Short brake	
L	L	Н	Н	OFF (High impedance)		Stop	
H/L	H/L	Н	L	OFF (High impedance)		Standby	

H-SW Operating Description

 \cdot To prevent penetrating current, dead time t2 and t4(300ns: Designed value) is provided in switching to each mode in the IC.

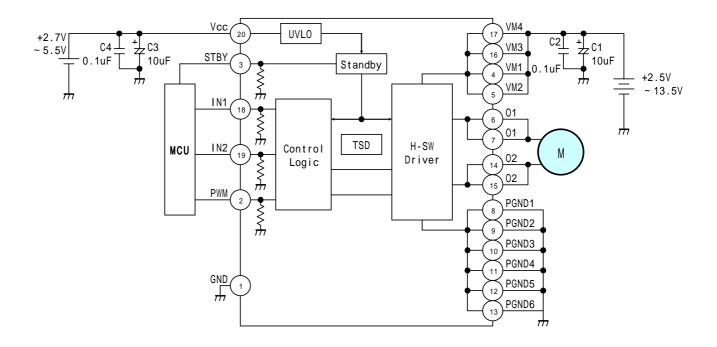




Electrical Characteristics (unless otherwise specified, $V_{CC}=3~V,~VM=4.5V,~Ta=25^{\circ}C$)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit	
	Icc	STBY=Vcc		0.9	1.2	mA	
Supply current	Icc(STB)	CIDN-01			1	μА	
	IM(STB)	STBY=0V			1		
Control input voltage	VIH		2		Vcc+0.2	V	
Control input voltage	VIL		-0.2		0.8	v	
Control input ourment	IIH	VIN=3V	5	15	25	A	
Control input current	IIL	VIN=0V			1	μA	
Ct and live investment and to me	VIH(STB)		2		Vcc+0.2	V	
Standby input voltage	VIL(STB)		-0.2		0.8	T V	
Ct Il itt	IIH(STB)	VIN=3V	5	15	25	1	
Standby input current	IIL(STB)	VIN=0V			1	μA	
Output saturating voltage	Vsat(U+L)	Io=1A		0.35	0.5	V	
Output leake de cument	IL(U)	VM=Vout=15V			1	Λ	
Output leakage current	IL(L)	VM=15V,Vout=0V	-1			μA	
Dogovovativa diada VE	VF(U)	IF=1A		1	1.1	V	
Regenerative diode VF	VF(L)	1r-1A		1	1.1		
Low voltage detecting voltage	UVLD	(Designed value)		2.0		V	
Recovering voltage	UVLC			2.2			
Thermal shutdown circuit operating temperature	TSD	(Designed value)		170			
Thermal shutdown hysteresis	ΔTSD	(Designed value)		20			

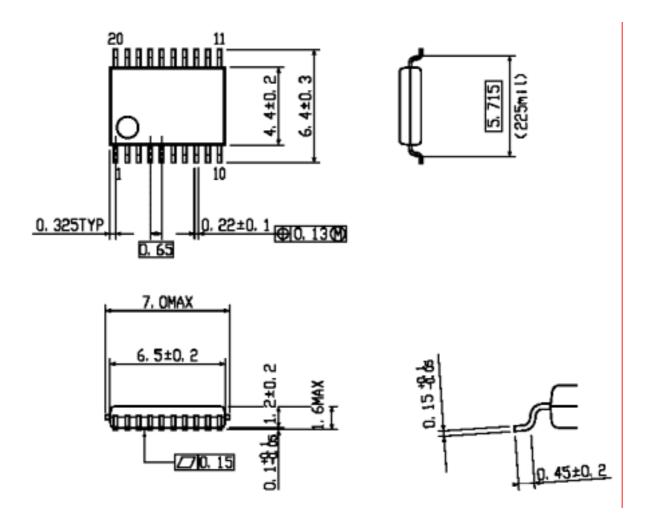
Typical Application Diagram



Note: The power supply capacitor should be connected as close as possible to the IC.

Package Dimennsions

SSOP20-P-225-0.65 Unit: mm



Weight: 0.09 g (Typ.)

Notes on Contents

1. Block Diagrams

Some of the functional blocks, circuits, or constants in the block diagram may be omitted or simplified for explanatory purposes.

2. Equivalent Circuits

The equivalent circuit diagrams may be simplified or some parts of them may be omitted for explanatory purposes.

3. Timing Charts

Timing charts may be simplified for explanatory purposes.

4. Maximum Ratings

The absolute maximum ratings of a semiconductor device are a set of specified parameter values which must not be exceeded during operation, even for an instant.

If any of these ratings are exceeded during operation, the device electrical characteristics may be irreparably altered and the reliability and lifetime of the device can no longer be guaranteed.

Moreover, these operations with exceeded ratings may cause breakdown, damage and/or degradation to other equipment. Applications using the device should be designed so that each maximum rating will never be exceeded in any operating conditions.

Before using, creating and/or producing designs, refer to and comply with the precautions and conditions set forth in this document.

5. Application Circuits

The application circuits shown in this document are provided for reference purposes only. Thorough evaluation is required, especially at the mass production design stage.

Toshiba does not grant any license to any industrial property rights by providing these examples of application circuits.

6. Test Circuits

Components in the test circuits are used only to obtain and confirm the device characteristics. These components and circuits are not guaranteed to prevent malfunction or failure from occurring in the application equipment.

About the handling of ICs

Install the product correctly to avoid breakdown, damage and/or degradation to the product or equipment.

About overcurrent protection and heat protection circuits

These protection functions are intended to guard against certain output short circuits or other abnormal conditions with only temporary effect, and are not guaranteed to prevent the IC from being damaged.

- These protection features may not be effective if the product is operated outside the guaranteed operating ranges, and some output short circuits may result in the IC being damaged.

The overcurrent protection feature is only intended to protect the IC from a temporary short circuit.

Short circuits of longer duration may damage the IC through undue stress. The systems must be configured so that any overcurrent condition will be eliminated as soon as possible.

Counter-electromotive force

When the motor reverses or stops, counter-electromotive force in the motor may influence the current to flow to the power source. If the power source lacks sink capability, the IC power and output pins may exceed the rating. The counter-electromotive force of the motor varies depending on the conditions of use and the features of the motor.

Therefore ensure that there is no damage to the IC or problem in operation, and no error in or damage to peripheral circuits resulting from counter-electromotive force.

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